

PROCEEDINGS OF SPIE

Optoelectronic Materials and Devices III

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Jens Buus
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Editors

27–30 October 2008
Hangzhou, China

Sponsored by

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Zhejiang University (China)

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Zhejiang Optical Society (China)

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Published by

SPIE

Volume 7135
Part One of Two Parts

Proceedings of SPIE, 0277-786X, v. 7135

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

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Please use the following format to cite material from this book:

Author(s), "Title of Paper," in *Optoelectronic Materials and Devices III*, edited by Yi Luo, Jens Buus, Fumio Koyama, Yu-Hwa Lo, Proceedings of SPIE Vol. 7135 (SPIE, Bellingham, WA, 2008) Article CID Number.

ISSN 0277-786X
ISBN 9780819473752

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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